## NSN 5961-01-309-6859

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-309-6859 **Inclosure Material:** Metal **Overall Length:** Between 1.092 inches and 1.131 inches **Overall Height:** Between 0.250 inches and 0.340 inches **Overall Width:** 0.750 inches **Function For Which Designed:** Amplifier **Mounting Facility Quantity: Internal Configuration:** Field effect **Electrode Internally-electrically Connected To Case:** Drain **Mounting Method:** Unthreaded hole **Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 drain to source voltage and 500.0 drain to gate voltage **Current Rating Per Characteristic:** 6.00 amperes drain current **Power Rating Per Characteristic:** 70.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No Fiig: A110a0